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High Quantum Efficiency of Nd^{3+} Ions in a Phosphate Glass System using the Judd–Ofelt Theory

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Abstract The optical properties of trivalent neodymium embedded in a $\text{P}_2\text{O}_5\text{--Al}_2\text{O}_3\text{--Na}_2\text{O--K}_2\text{O}$ phosphate glass system, synthesized by the fusion method, are studied. Absorption, luminescence, lifetime, and Raman spectroscopy measurements were performed and the Judd–Ofelt theory was applied to determine optical parameters such as the quantum efficiency and the stimulated emission cross section of the Nd^{3+} -doped glass system. This structure has high quantum efficiency at low Nd^{3+} concentrations, comparable to the efficiency of a commercial YAG:Nd^{3+} crystal. We discuss the mechanisms responsible for the high quantum efficiency observed in the proposed phosphate glass system.

Keywords High quantum efficiency · Nd^{3+} ions · Phosphate glass system · Judd–Ofelt Theory

1 Introduction

In recent decades, glass systems doped with rare earth (RE) ions have attracted attention due to their mechanical stability,

low cost, low conductivity, and thermal properties that are desirable in optical devices with diverse applications [1–6].

Neodymium is the most widely studied doping agent because of its use in neodymium lasers that are highly efficient, even at room temperature [7–9]. However, non-radiative energy transfer by cross relaxation between Nd^{3+} ions, phonon charge losses to the glass network, and energy transfer from Nd^{3+} ions to OH^- and CH radicals reduce quantum efficiency and are obstacles to the development more efficient systems [10–12]. Several researchers have pointed out that SiO_2 is not a suitable host because rare earth ions in the glass tend to form clusters in the silica network. These clusters cause quenching of luminescence due to energy transfer between neighboring ions [10, 11]. Thus, researchers continue to develop new glass systems, with different spectroscopic parameters, for optical device applications [12–15].

In this paper, we report the optical properties of Nd^{3+} ions embedded in a PANK ($\text{P}_2\text{O}_5\text{--Al}_2\text{O}_3\text{--Na}_2\text{O--K}_2\text{O}$) phosphate glass system synthesized by the fusion method at different Nd^{3+} concentrations. Absorption, luminescence, lifetime, and Raman spectroscopy measurements were performed, and the Judd–Ofelt theory [16, 17] was applied to determine optical parameters such as quantum efficiency and the stimulated emission cross section of the Nd^{3+} -doped glass system. The proposed Nd^{3+} -doped PANK glass system has high quantum efficiency at low Nd^{3+} concentrations, and the fluorescence lifetime and quantum efficiency of the $^4\text{F}_{3/2}$ state decrease as the Nd^{3+} concentration increases.

2 Theoretical Details

The Judd–Ofelt (JO) theory has been used as a fundamental framework for quantitative spectroscopic analysis of RE ions embedded in different environments. According to

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the Judd–Ofelt theory, electric dipole oscillator strength between electronic transitions from initial $\langle f^N \alpha SLJ |$ to final state $|f^N \alpha' S' L' J'\rangle$ can be expressed as [16, 17]

$$f^{ED}(J, J') = \frac{8\pi^2 mc}{3h} \frac{E}{(2J+1)} \chi \sum_{\lambda=2,4,6} \Omega_{\lambda} |\langle f^N \alpha SLJ | U^{(\lambda)} | f^N \alpha' S' L' J' \rangle|^2 \quad (1)$$

where m is electron mass, c is the speed of light, E is the electronic transition energy, h is Planck's constant, J is the angular momentum of the initial state $\langle f^N \alpha SLJ |$, $\chi = (n^2 + 2)^2 / (9n)$ is the central field correction factor, n is the refractive index at wavenumber E , Ω_{λ} is the Judd–Ofelt intensity parameter, and $|\langle f^N \alpha SLJ | U^{(\lambda)} | f^N \alpha' S' L' J' \rangle|^2$ is the reduced matrix element of the tensor operator $U^{(\lambda)}$ obtained from the Carnall et al. calculation [18–20].

The JO intensity parameters Ω_{λ} ($\lambda=2, 4, 6$) can be used to estimate optical quantities such as spontaneous emission probability ($A(J, J')$), branching ratio ($\beta(J, J')$), stimulated emission cross section ($\sigma(J, J')$), radiative lifetime ($\tau_R(J, J')$), and quantum efficiency (η). These parameters can then be used to predetermine if an RE ion host material is favorable for optical device applications [12, 13]. The Ω_2 parameter, for example, is related to covalency between RE³⁺ ions and ligand anions in the glass environment. It is also associated with the asymmetry of the local environment around RE³⁺ ions. Low values of Ω_2 indicate higher symmetry and higher ionicity of the ligand chemical bonds [21–28].

Judd–Ofelt parameters, Ω_{λ} ($\lambda=2, 4, 6$) can be experimentally obtained from experimental oscillator strengths via the expression

$$f^{\text{exp}}(\lambda) = \frac{mc}{\pi e^2 N} \int \alpha(\lambda) d\lambda, \quad (2)$$

where N is the RE ion concentration per unit volume (ions per cubic centimeter), and $\alpha(\lambda)$ is the absorption coefficient. Using Eq. (2) with Eq. (1), it is possible to obtain Ω_{λ} .

The Ω_{λ} parameters can then be used to calculate radiative transition rates ($A(J, J')$) with the expression

$$A(J, J') = \frac{64 \pi^4 e^2}{3h(2J+1)\lambda^3} \chi \sum_{\lambda=2,4,6} \Omega_{\lambda} |\langle f^N \alpha SLJ | U^{(\lambda)} | f^N \alpha' S' L' J' \rangle|^2 \quad (3)$$

The radiative lifetime τ_R of the emission state is given as $\tau_R = 1 / \sum_{J'} A(J, J')$.

The emission branching ratio for transitions originating from the initial manifold is related to the radiative transition rates, $A(J, J')$, by the following equation [1, 12, 13]:

$$\beta(^4F_{3/2} \rightarrow ^4I_{J'}) = \frac{A(^4F_{3/2} \rightarrow ^4I_{J'})}{\sum_{J'} A(^4F_{3/2} \rightarrow ^4I_{J'})} \quad (4)$$

where the summation includes each J' ($J'=9/2, 11/2, 13/2$, and $15/2$).

To compare theoretical data obtained from Eq. (4) with experimental data, the ratio of the integral of an emission band, $\int I(\lambda) d\lambda$, to the sum of the integrals of all emission bands, $\sum \int I(\lambda) d\lambda$, is calculated. This results in the experimental emission branching ratio represented by $\beta_{\text{exp}} = \int I(\lambda) d\lambda / \sum \int I(\lambda) d\lambda$.

The stimulated emission cross section is another important parameter that provides interesting information about the laser performance of a material and can be easily determined from luminescence properties [29]. The spontaneous emission cross section between $^4F_{3/2} \rightarrow ^4I_{J'}$ is represented by the equality [1, 13, 30]:

$$\sigma_{em}(^4F_{3/2} \rightarrow ^4I_{J'}) = \frac{\lambda_p^4}{8\pi c n \Delta\lambda_{\text{eff}}} A(^4F_{3/2} \rightarrow ^4I_{J'}), \quad (5)$$

where λ_p is the peak emission wavelength, c is the speed of light in a vacuum, n is the refractive index at each emission peak wavelength, and $\Delta\lambda_{\text{eff}}$ is the effective emission linewidth. The effective linewidth is used instead of the full width at half maximum linewidth because the emission band is asymmetric. This parameter is represented by [1, 12, 13, 30]: $\Delta\lambda_{\text{eff}} = \int I_{PL}(\lambda) d\lambda / I_{PL}^{\text{max}}$. Here, I_{PL}^{max} is the maximum intensity at fluorescence emission peaks.

Once the radiative parameters are known, non-radiative losses and quantum efficiency can be determined. The quantum efficiency (η) is obtained from lifetime measurements: $\eta = \tau_{\text{exp}} / \tau_R$. Here, τ_{exp} is the experimental lifetime, and τ_R is the calculated lifetime from the Judd–Ofelt theory.

3 Experimental Procedure

Two sets of PANK matrices with nominal composition $40\text{P}_2\text{O}_5 \cdot 20\text{Al}_2\text{O}_3 \cdot 35\text{Na}_2\text{O} \cdot 5\text{K}_2\text{O}$ (in mole percent) were synthesized by the fusion method. These were undoped and doped with Nd³⁺ ions, resulting in PANK and PANK+ $x\text{Nd}_2\text{O}_3$ (in weight percent), with $x=1; 2; 3; 4; 5; 6$. This glass system results from combining a network-forming oxide P_2O_5 with network modifier oxides Na_2O and K_2O and an intermediate oxide Al_2O_3 . The P_2O_5 oxide is optically transparent and increases thermal stability. The Na_2O oxide reduces the melting point and increases glass system homogenization by reducing defects and bubbles. The Al_2O_3 and K_2O oxides are added to increase chemical resistance, reduce hydroxyl (O–H)[−] group density, and improve mechanical properties.

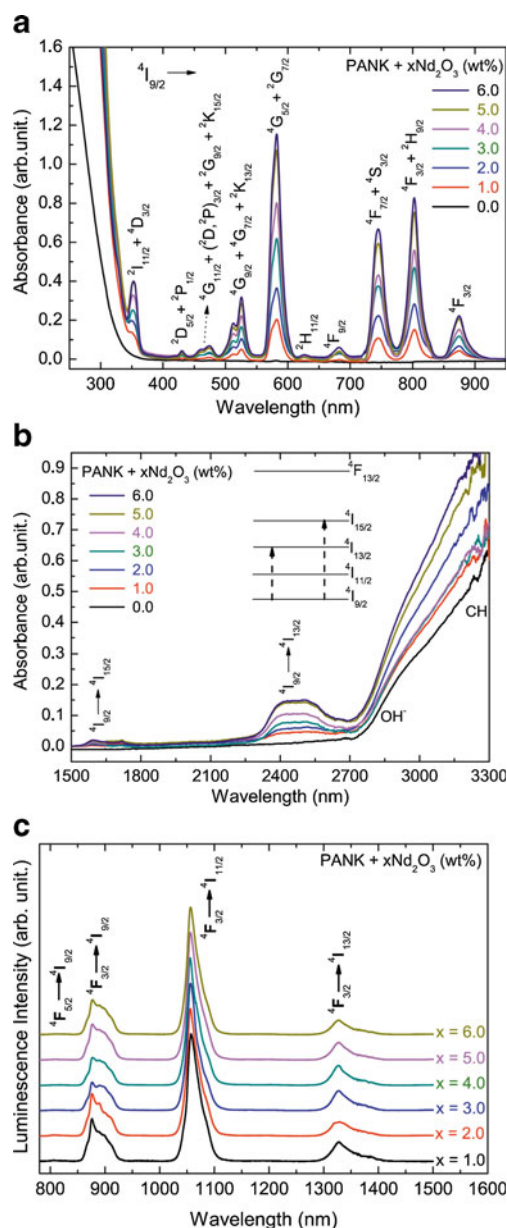
The powder was melted in porcelain crucibles and in a carbon-rich atmosphere for 30 min at 1,350 °C. The melt was then rapidly cooled between graphite plates in an oven at 250 °C. The resulting blades were heated at 350 °C for 48 h to partially remove internal stresses. The melt was manually rotated at least three times inside the crucible. This procedure was effective because the optical density absorption measurements, taken at various points during sample preparation,

demonstrate sample homogeneity. All of the samples underwent lengthy and meticulous polishing to minimize surface roughness (flat nanosurface) and make the sides parallel. The samples were also cleaned immediately prior to optical absorption (OA), photoluminescence (PL), and time-resolved photoluminescence (TRPL) measurements to avoid surface contamination. OA was determined using a Shimadzu UV-3600 spectrophotometer, and samples were excited by Ar^+ ($\lambda_{\text{exc}}=514 \text{ nm}$) and diode ($\lambda_{\text{exc}}=532 \text{ nm}$) lasers for PL and TRPL spectra, respectively. A thermoelectrically cooled GaInAs pin photodiode and a standard lock-in technique were used to collect PL measurement spectra at NIR wavelengths. TRPL measurements were recorded using a digital phosphor oscilloscope (Tektronix DPO 2012, 100 MHz, 1 GS/s) and detected with a Si PIN photodiode operating in the photoconductive mode in the 200- to 1,100-nm range. All characterizations were performed at room temperature.

The ion density, N (ions per cubic centimeter), was evaluated by $N(\text{ions}/\text{cm}^3) = x\rho N_A/M$, where ρ is the density of the glass, N_A is Avogadro's number, x is the mole fraction of rare earth oxide, and M is the average molecular weight of the glass [12].

4 Results and Discussion

Figure 1 shows the absorbance and luminescence spectra of the PANK and $\text{PANK} + x\text{Nd}_2\text{O}_3$ (in weight percent) glass systems in the electromagnetic spectrum (Fig. 1a, UV–VIS–NIR; Fig. 1b, IR; and Fig. 1c, NIR spectral range). Allowed Nd^{3+} electronic transitions are visible in the UV–VIS–IR spectral range due to the high optical band-gap energy of the PANK glass system. For low Nd^{3+} concentrations, Fig. 1a shows that the optical band-gap energy red shifts with increasing Nd^{3+} concentrations (3.906 eV for $x=0$ and 3.826 eV for $x=1\%$). This shift probably occurs because the ionic radius of Nd^{3+} is higher relative to other elements in the glass, causing rearrangement of the glass structure. The optical density of the OH^- band in Fig. 1b is lower than in other vitreous systems such as SNAB ($\text{SiO}_2\text{--Na}_2\text{O--Al}_2\text{O}_3\text{--B}_2\text{O}_3$). The SNAB system has low quantum efficiency associated with the OH^- band [1]. This indicates that energy transfer from Nd^{3+} ion states to the OH^- band can be neglected in PANK and that the allowed electronic transition, $^4I_{9/2} \rightarrow ^4I_{15/2}$, of the Nd^{3+} ions in $\text{PANK} + x\text{Nd}_2\text{O}_3$ (in weight percent) is more intense relative to the SNAB glass system [1]. This may result in a system with high quantum efficiency. Figure 1c shows the luminescence spectra of the Nd^{3+} ions in the PANK system at room temperature. Here, the shape of the bands at about 900 nm is modified as Nd_2O_3 concentration increases. This indicates that allowed Nd^{3+} electron transitions are influenced by the rearrangement of the system caused by Nd^{3+} .



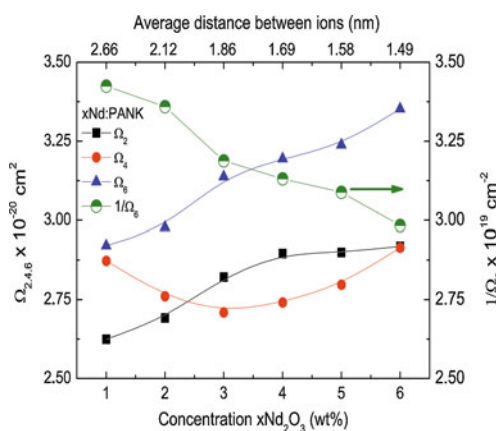


Fig. 2 Judd–Ofelt $\Omega_{2,4,6}$ and $1/\Omega_6$ parameters as function of Nd_2O_3 concentration in the PANK system

reciprocal value ($1/\Omega_6$) gives information on the ionicity around the RE^{3+} ions [31–33]. Increasing Ω_4 with rising Nd_2O_3 concentrations indicates possible far-reaching impacts on the host matrix in the vicinity of Nd–O [12, 33]. Low concentrations of Nd^{3+} ($0 < x < 3$) rearrange the network, which reduces these repulsive forces. High Nd^{3+} concentrations ($3 \leq x \leq 6$) lead to a splitting of Nd^{3+} levels by a crystal field including the contributions from neighboring Nd^{3+} ions. This contributes to the increasing of the Ω_4 parameter. This behavior has been observed in other glass systems [33] and can be seen in the luminescence spectra (Fig. 1c) where the shape of the band centered at 900 nm is heavily modified as Nd_2O_3 (in weight percent) concentration increases from 2 to 3.

It is known that Ω_6 decreases as the mechanical rigidity of a system increases [1, 31, 32]. The Ω_6 of the PANK system (see Fig. 2) was higher than that observed in the SNAB system ($\Omega_6 \sim 0.8 \times 10^{-20} \text{ cm}^2$) [1]. Thus, PANK tends to be less rigid than SNAB and other glass systems (see Table 1). It is also known that the inverse of Ω_6 [1, 43, 44] is proportional to the ionicity of the ion in the ligand field [1, 43, 44]. Lower $1/\Omega_6$ values indicate a less ionic and more covalent bond. Figure 2 shows that $1/\Omega_6$ decreases as Nd_2O_3 concentration increases in the PANK glass system. In other words, Nd^{3+} ionicity decreases in the ligand field as Nd_2O_3 concentration increases in the glass system host. However, increasing concentration modifies the crystal field potential by breaking the surrounding symmetry (increasing Ω_2) and increasing ion covalence (see Table 1).

Figure 3 shows the calculated and experimental emission branching ratios or transition probabilities of allowed electronic transitions as a function of Nd^{3+} concentration. These experimental and calculated values are in good agreement. The probability of a ${}^4\text{F}_{3/2} \rightarrow {}^4\text{I}_{15/2}$ transition was estimated from the OA spectra. The result (0.35 %) suggests very low luminescence intensity from the ${}^4\text{F}_{3/2} \rightarrow {}^4\text{I}_{15/2}$ transition that was undetectable in the electromagnetic spectrum given equipment limitations.

Figure 4 shows the dependence of experimental and calculated fluorescence lifetime and quantum efficiency of the ${}^4\text{F}_{3/2}$ state with increasing Nd^{3+} concentration. Quantum efficiency was high (98 %) in the proposed Nd^{3+} -doped PANK glass system at low Nd^{3+} concentrations. It can be seen that both the fluorescence lifetime and quantum efficiency of the ${}^4\text{F}_{3/2}$ state decrease as Nd^{3+} concentration increases. The high quantum efficiency of the Nd^{3+} -doped PANK glass system was recently confirmed by the thermal lens technique [45].

It is known that non-radiative processes reduce the lifetime of radiative transitions. These processes are governed by energy transfers from RE ions to the host material (e.g., network vibrational modes, OH and CH radicals, and cross-relaxation process (ion–ion interaction)) [1]. The multiphonon relaxation rate [13, 46] for the ${}^4\text{F}_{3/2}$ level should be low, as will be shown later [1]. Thus, the short experimental lifetime of the samples at higher Nd^{3+} concentrations is probably due to excited energy migration between Nd^{3+} ions and, to a lesser extent, energy transfer to unintentionally introduced impurities and/or defects near the Nd^{3+} ions.

Considering the non-radiative transition processes from the ${}^4\text{F}_{3/2}$ Nd^{3+} level, namely resonant energy migration processes between Nd^{3+} ions (cross relaxation), it can be seen that resonance only occurs from ${}^4\text{F}_{3/2} \rightarrow {}^4\text{I}_{13/2}$ to ${}^4\text{F}_{3/2} \rightarrow {}^4\text{G}_{7/2}$, ${}^4\text{F}_{3/2} \rightarrow {}^4\text{I}_{11/2}$ to ${}^4\text{F}_{3/2} \rightarrow {}^4\text{G}_{11/2}$, and ${}^4\text{F}_{3/2} \rightarrow {}^4\text{I}_{9/2}$ to ${}^4\text{F}_{3/2} \rightarrow {}^2\text{D}_{11/2}$. The JO theory allows these transitions for Nd–Nd interactions. The distance between ions at low Nd concentrations is great and therefore does not allow interaction between dipoles [47–49]. As the distance between dipoles decreases, interactions between dipoles become stronger and RE ion concentration increases. The reduction in experimental lifetime of the ${}^4\text{F}_{3/2}$ state with increasing Nd_2O_3 concentration has been thoroughly studied by Stokowski using the empirical ratio [50]:

$$\tau_{\text{exp}} = \frac{\tau_o}{1 + (N/Q)^n} \quad (8)$$

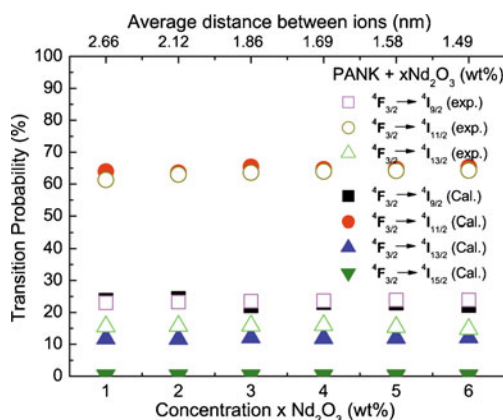
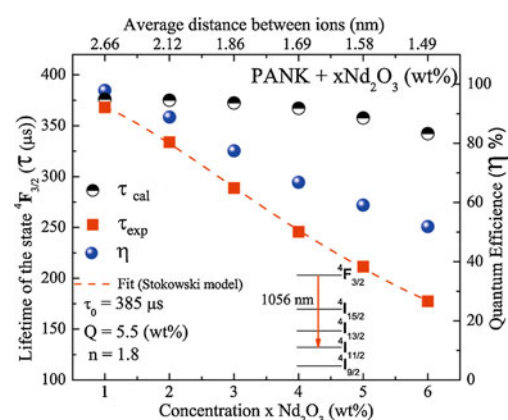
where τ_o is the observed lifetime for a diluted system, Q is the Nd concentration at $\tau = \tau_o/2$, and n is an adjustable parameter. In glass doped with Nd^{3+} , n near two occurs when fluorescence quenching is dominated by cross-relaxation processes. A high Q value results in an optically efficient system. In the present study, good fit was obtained using $\tau_o = 385 \mu\text{s}$, $Q = 5.5 \text{ Nd}_2\text{O}_3$ (weight percent) (approximately $2.5 \times 10^{20} \text{ ions/cm}^3$), and $n = 1.8$ (dashed red line, Fig. 4). This indicates that PANK is similar to CANB ($52\text{CaO} \cdot 36\text{Al}_2\text{O}_3 \cdot 6\text{Na}_2\text{O} \cdot 6\text{BaO} \cdot 0.5\text{Nd}_2\text{O}_3$), CANS ($52\text{CaO} \cdot 36\text{Al}_2\text{O}_3 \cdot 6\text{Na}_2\text{O} \cdot 6\text{SrO} \cdot 0.5\text{Nd}_2\text{O}_3$), LSCA ($47.4\text{CaO} \cdot (41.5-x)\text{Al}_2\text{O}_3 \cdot 7.0\text{SiO}_2 \cdot 4.1\text{MgO}$, where x varied from 0.5 to 5.0 (in weight percent)), ED-2 (Li–Ca–Al silicate commercial glasses—Owens-Illinois), and YAG (yttrium aluminum garnet) systems [6, 34, 36, 51–53]. The good fit and high n ($n \approx 2$) and Q parameters suggest that energy transfer is primarily due to cross relaxation.

Table 1 JO ($\times 10^{-20} \text{ cm}^2$) parameters, quantum efficiency (in percent), and stimulated emission section ($\times 10^{-20} \text{ cm}^2$) for various materials such as crystals, glass systems, films, and polymers with low Nd^{3+} concentrations

Host	Ω_2	Ω_4	Ω_6	Quantum efficiency	Emission section	Reference
CANB glass	4.46	5.18	2.73	80	1.32	[34]
CANS glass	3.71	5.03	2.90	75	1.32	[34]
CASGAR garnet	0.98	3.20	3.63	—	—	[35]
YAG: Nd^{3+} (single crystal)	0.20	2.70	5.00	96.1	100	[36, 37]
ED-2	3.30	4.68	5.18	78	2.71	[34]
LSCA	3.21	4.07	2.01	93	2.19	[6]
NYCaB10	4.66	10.34	10.32	—	—	[38]
PbO– Bi_2O_3 – Ga_2O_3 –BaO	3.2	2.7	3.1	80	—	[39]
Fluoroaluminate glass	1.97	3.43	5.38	—	—	[40]
Phosphate (KBAP)	3.42	4.09	4.35	60	2.3	[41]
Fluorophosphate (A)	2.57	4.40	5.99	41	3.69	[41]
Fluoride	1.21	2.54	4.19	40	1.87	[41]
Sulfide	—	—	—	36	—	[41]
Fluorophosphate (2 wt.%)	1.83	4.73	4.19	60	2.68	[41]
PMMA	2.11	3.78	2.61	—	—	[42]
PMMA	38	3.58	4.71	—	1.87	[42]
HEMA	7.78	4.26	7.19	—	—	[42]
POF	0.83	1.64	4.04	—	1.21	[42]
ZBLAN	2.66	3.05	4.08	—	2.9	[42]
YAG: Nd^{3+} (ceramic)	0.22	3.55	5.33	88.8	29.7	[36, 37]
YAG: Nd^{3+} (ceramic)	0.22	2.57	3.71	77.5	17.3	[36]
Poly(styrene sulfonate) (PSS) films	3.0	10.5	10.5	—	1.21	[42]
SNPZ	3.66	5.53	2.73	93	—	[30]
SNAB	1.2	2.3	0.8	25	1.2	[1]
SBP glass	1.0–2.0	0.5–1.6	0.8–2.4	—	1.0–3.0	[33]
SBP ceramic–glass	1.0–2.5	0.6–1.3	1.1–2.2	—	1.3–2.6	[33]
PANK	2.62	2.87	2.92	98	4.12	This work

The ratio (${}^4\text{F}_{3/2} \rightarrow {}^4\text{I}_{13/2}$)/(${}^4\text{F}_{3/2} \rightarrow {}^4\text{G}_{7/2}$) is 0.99. This suggests a resonant system that allows energy transfer by cross relaxation. Other transitions occur at lower intensities because of lower energy ratios (e.g., 0.98 for the

${}^4\text{F}_{3/2} \rightarrow {}^4\text{I}_{11/2}$ to ${}^4\text{F}_{3/2} \rightarrow {}^4\text{G}_{11/2}$ transition and 0.97 for ${}^4\text{F}_{3/2} \rightarrow {}^4\text{I}_{9/2}$ to ${}^4\text{F}_{3/2} \rightarrow {}^2\text{D}_{11/2}$). The ${}^4\text{F}_{3/2} \rightarrow {}^4\text{I}_{13/2}$ transition probably has the greatest effect on luminescence quenching due to greater resonance.

**Fig. 3** Calculated and experimental probability of the allowed electronic luminescence transitions in the PANK system**Fig. 4** Theoretical and experimental lifetime, and quantum efficiency, of the ${}^4\text{F}_{3/2}$ state of Nd^{3+} in the PANK system

As previously mentioned, energy transfer to OH^- and CH radicals via phonons exists in the vitreous network. The literature reports that phosphate-based glass systems have high vibrational modes [54] that also decrease experimental lifetime and quantum efficiency [30]. Infrared absorption measurements were performed to further investigate these hypotheses. Figure 1b shows the far-infrared spectra of the PANK glass system doped with different concentrations of Nd_2O_3 . Here, very weak absorption is visible at approximately 2,790 nm ($3,584\text{ cm}^{-1}$), which is characteristic of OH^- radicals [55]. There also appears to be a band edge centered at 3,450 nm ($2,900\text{ cm}^{-1}$) that can be associated with the vibration mode of CH radicals [56]. The presence of these radicals in the PANK glass system causes energy transfers via non-radiative electronic transitions from Nd^{3+} ions that reduce experimental lifetime of the $^4\text{F}_{3/2}$ state [1]. This energy transfer mechanism is not so favored because energy differences between Nd^{3+} states do not have an integer number of phonons (see below) [13, 46].

Non-radiative transition losses are determined by considering that the total transition rate ($W_T = 1/\tau_{\text{exp}}$) is the sum of the radiative rates ($W_R = 1/\tau_R$) and all non-radiative (W_{NR}) mechanisms such as multiphonon decay, cross relaxation between Nd^{3+} ions, and energy transfer between Nd^{3+} ions and impurities (OH^- or CH radicals and other quenching centers). The inverse of the total transition rate corresponds to the inverse of experimental lifetime: $W_T = W_R + W_{\text{NR}}$, $\rightarrow W_{\text{NR}} = (1/\tau_{\text{exp}}) - (1/\tau_R)$. The multiphonon relaxation rate can be estimated by the empirical relation [13, 57]:

$$W_{\text{NR}} = W_{\text{MP}}(T) = C_p \frac{\exp[-\alpha \Delta E]}{\{1 - \exp[\hbar\omega / (K_B T)]\}^p} \quad (12)$$

where C_p and α are host-dependent non-radiative parameters, ΔE is the energy gap between two successive levels, and $p = \Delta E / (\hbar\omega)$ is the number of phonons emitted in the relaxation process. This process is more efficient when p is a small integer number. In borosilicate glass doped with Nd^{3+} ions, for example, the multiphonon emission process from the $^4\text{F}_{3/2}$ level to the $^4\text{I}_{13/2}$ level, $\Delta E = 7,519\text{ cm}^{-1}$, requires approximately seven ($p = 7.09$) phonon emissions because the maximum phonon energy in borosilicate glass is $\hbar\omega = 1,060\text{ cm}^{-1}$. Thus, the multiphonon relaxation rate for the $^4\text{F}_{3/2}$ level is expected to be low in borosilicate glass [1]. In our sample, the phonons emitted in the relaxation process corresponding to the $^4\text{F}_{3/2} \rightarrow ^4\text{I}_{9/2}$, $^4\text{F}_{3/2} \rightarrow ^4\text{I}_{11/2}$, and $^4\text{F}_{3/2} \rightarrow ^4\text{I}_{13/2}$ transitions of Nd^{3+} ions are respectively, $p = 3.3$, 2.7, and 2.2 for OH^- phonons and $p = 3.9$, 3.2, and 2.6 for CH phonons. Thus, energy migration followed by quenching in OH^- and CH results in negligible lifetime reduction.

Pemberton et al. [58] studied Raman spectra in metaphosphate glasses and found a medium-to-strong intensity band at $690\text{--}700\text{ cm}^{-1}$ for the $\nu_s(\text{POP})$ vibration, a strong band at $1,178\text{--}1,168\text{ cm}^{-1}$ for the $\nu_s(\text{PO}_2)$ vibration, and a medium-to-weak band at $1,260\text{--}1,280\text{ cm}^{-1}$ for the $\nu_{\text{as}}(\text{PO}_2)$ vibration. The positions of these bands are sensitive to phosphate chain length. In particular, the somewhat more intense peak at approximately $1,160\text{ cm}^{-1}$ is due to symmetric stretching of the nonbridging oxygen in Q_2 phosphate groups [59]. The same mechanism for energy transfer to the OH^- and CH radicals is valid for the network vibration in which the $^4\text{F}_{3/2} \rightarrow ^4\text{I}_{9/2}$, $^4\text{F}_{3/2} \rightarrow ^4\text{I}_{11/2}$, and $^4\text{F}_{3/2} \rightarrow ^4\text{I}_{13/2}$ transitions of the Nd^{3+} ions correspond, respectively, to $p = 9.8$, 8.2, and 6.5 of the most intense vibrational mode of the phosphate glasses.

In summary, our results demonstrate that luminescence transitions of the Nd^{3+} ions are not resonant with the vibrational modes of the network and OH^- and CH radicals, and explain the high efficiency of the PANK glass system doped with Nd^{3+} ions. This is due to the low rate of energy transfer to vibrational modes of the glass network and OH^- and CH radicals. Ion-ion interactions are responsible for reductions in experimental lifetime as Nd concentration increases (as in Stokowski's model) [50]. The highest efficiency value, at the lowest Nd^{3+} ion concentration, is comparable to that of the YAG:Nd^{3+} crystal [36, 37] (Table 1). For example, quantum efficiency varies from 45 to 60 % at concentrations up to 2 mol% in LiFP and BaFP glass fluorophosphates [60]. This suggests that the PANK system is a strong candidate for laser device applications.

The stimulated emission cross section provides useful information about the potential laser performance of a material and can be easily evaluated using luminescence properties [29]. Its value signifies the rate at which energy is extracted from the lasing material. Previous studies [61] have

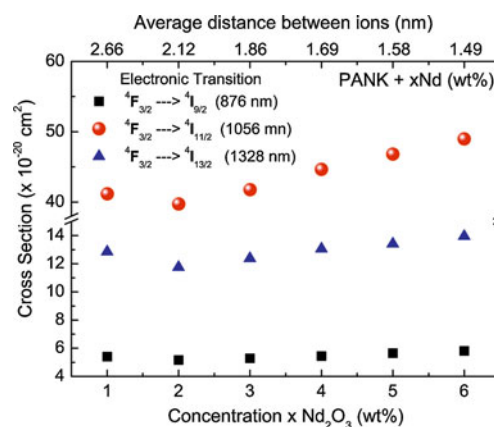


Fig. 5 Stimulated emission section of the allowed electronic transitions ($^4\text{F}_{3/2} \rightarrow ^4\text{I}_{9/2,11/2,13/2}$) as a function of Nd_2O_3 concentration in the PANK system

shown that the stimulated emission cross section can increase as the refractive index of a glass host increases. This change is due to increases in the electric dipole transition of rare earth ions as the refractive index of the glass host increases. Good laser transitions are characterized by large stimulated emission cross sections [22, 41, 62]. Figure 5 shows a section of the stimulated emission, $\sigma(^4F_{3/2} \rightarrow ^4I_r)$, as a function of Nd_2O_3 concentration in the PANK glass system. The sequence of these section values is $\sigma(^4F_{3/2} \rightarrow ^4I_{11/2}) > \sigma(^4F_{3/2} \rightarrow ^4I_{13/2}) > \sigma(^4F_{3/2} \rightarrow ^4I_{9/2})$. The $^4F_{3/2} \rightarrow ^4I_{11/2}$ section is somewhat dependent on concentration. In this case, the $\sigma(^4F_{3/2} \rightarrow ^4I_{11/2})$ section of the Nd^{3+} ions varies between 40 and $50 \times 10^{-21} \text{ cm}^2$. These values are near those of other systems at concentrations up to 2 mol% (e.g., LiFP $\sigma(^4F_{3/2} \rightarrow ^4I_{11/2}) = 67 \times 10^{-21} \text{ cm}^2$ and commercially available fluorophosphate laser glass L-223 $\sigma(^4F_{3/2} \rightarrow ^4I_{11/2}) = 35 \times 10^{-21} \text{ cm}^2$) [60] (Table 1). The mechanism promoting stimulated emissions becomes more efficient when the distance between identical ions decreases. Peak cross sections are dependent on intensity parameters, Ω_λ , and the bandwidth, $\Delta\lambda_{\text{eff}}$. Both are affected when composition changes. The effective bandwidth is a measure of the overall extent of the Starks splitting of the J manifolds and is inhomogeneous due to the site-to-site variations in the local fields with which the rare earth ion interacts.

5 Conclusions

Nd^{3+} ions embedded in a PANK phosphate glass system were synthesized by the fusion method. Optical properties of this system were studied by optical absorption, photoluminescence, and lifetime measurements. Judd–Ofelt parameters, radiative rates, lifetime, branching ratios, and the emission cross section were calculated. Quantum efficiency of the Nd^{3+} -doped PANK glass system is high (98 %) at low Nd^{3+} concentrations. Additionally, fluorescence lifetime and quantum efficiency of the $^4F_{3/2}$ state decrease as Nd^{3+} concentration increases.

At the lowest concentration (1 % Nd^{3+}), quantum efficiency is highest and comparable to that of a YAG: Nd^{3+} crystal. The stimulated emission section of Nd^{3+} -doped PANK glass is higher than other glass and crystal systems, making it an attractive option for the optical cavities of highly efficient laser systems. Reduction in the experimental lifetime of the $^4F_{3/2} \rightarrow ^4I_{11/2}$ transition with increasing Nd_2O_3 concentration was attributed to non-radiative energy transfer by cross relaxation between Nd^{3+} ions and phonon charge losses to the glass network. Non-radiative energy transfer from Nd^{3+} ions to OH^- and CH radicals can be disregarded because $^4F_{3/2} \rightarrow ^4I_{11/2}$ electronic transition energy does not correspond with the vibration frequency multiples of these radicals. Finally, it was concluded that cross relaxation also decreases the lifetime of the $^4F_{3/2}$

Nd^{3+} level. We believe that these results may inspire further investigation and possible device applications.

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